



# PJX8872B

## 60V N-Channel Enhancement Mode MOSFET

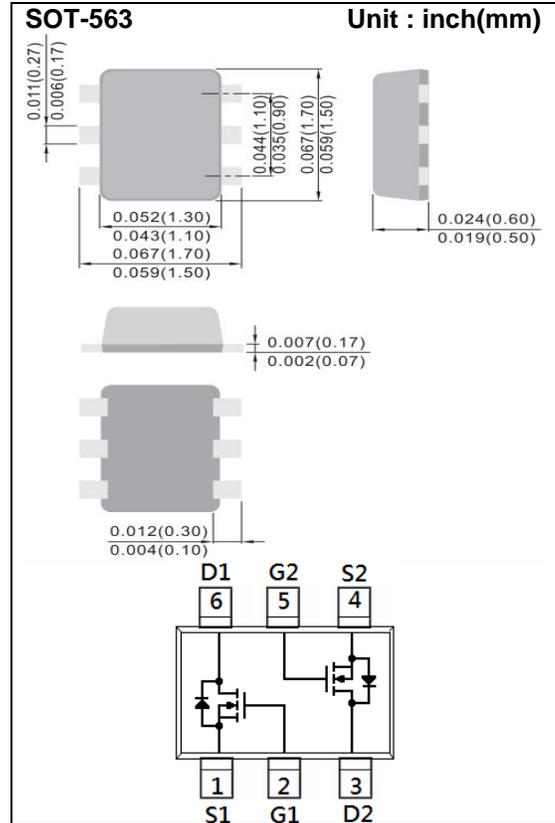
**Voltage** 60 V **Current** 200mA

### Features

- RDS(ON) , VGS@10V, ID@600mA<3Ω
- RDS(ON) , VGS@4.5V, ID@200mA<4Ω
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case: SOT-563 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00009 ounces, 0.0026 grams



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

| PARAMETER  | SYMBOL                            | LIMIT                | UNITS |
|--|-----------------------------------|----------------------|-------|
| Drain-Source Voltage                             | V <sub>DS</sub>                   | 60                   | V     |
| Gate-Source Voltage                              | V <sub>GS</sub>                   | +30                  | V     |
| Continuous Drain Current                         | I <sub>D</sub>                    | 200                  | mA    |
| Pulsed Drain Current                             | I <sub>DM</sub>                   | 800                  | mA    |
| Power Dissipation                                | P <sub>D</sub>                    | T <sub>A</sub> =25°C | 300   |
|  |                                   | Derate above 25°C    | 4     |
| Operating Junction and Storage Temperature Range | T <sub>J</sub> , T <sub>STG</sub> | -55~150              | °C    |
| Typical Thermal Resistance                       | R <sub>θJA</sub>                  | 417                  | °C/W  |
| - Junction to Ambient <sup>(Note 3)</sup>        |                                   |                      |       |



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

| PARAMETER   | SYMBOL       | TEST CONDITION  | MIN. | TYP. | MAX.      | UNITS    |
|---|--------------|---|------|------|-----------|----------|
| <b>Static</b>   |              |   |      |      |           |          |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$   | 60   | -    | -         | V        |
| Gate Threshold Voltage                                | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$   | 1.0  | 1.8  | 2.5       | V        |
| Drain-Source On-State Resistance                      | $R_{DS(on)}$ | $V_{GS}=10V, I_D=600mA$   | -    | 1.3  | 3         | $\Omega$ |
|   |              | $V_{GS}=4.5V, I_D=200mA$  | -    | 1.7  | 4         |          |
| Zero Gate Voltage Drain Current                       | $I_{DSS}$    | $V_{DS}=60V, V_{GS}=0V$   | -    | -    | 1         | $\mu A$  |
| Gate-Source Leakage Current                           | $I_{GSS}$    | $V_{GS}=\pm 30V, V_{DS}=0V$   | -    | -    | $\pm 100$ | nA       |
| <b>Dynamic</b> (Note 4)                               |              |   |      |      |           |          |
| Total Gate Charge                                     | $Q_g$        | $V_{DS}=15V, I_D=600mA,$<br>$V_{GS}=4.5V$                             | -    | 0.82 | -         | nC       |
| Gate-Source Charge                                    | $Q_{gs}$     |   | -    | 0.53 | -         |          |
| Gate-Drain Charge                                     | $Q_{gd}$     |   | -    | 0.22 | -         |          |
| Input Capacitance                                     | $C_{iss}$    | $V_{DS}=25V, V_{GS}=0V,$<br>$f=1.0MHz$                                | -    | 34   | -         | $\mu F$  |
| Output Capacitance                                    | $C_{oss}$    |   | -    | 11   | -         |          |
| Reverse Transfer Capacitance                          | $C_{rss}$    |   | -    | 3.0  | -         |          |
| Turn-On Delay Time                                    | $t_{d(on)}$  | $V_{DD}=10V, I_D=600mA,$<br>$V_{GS}=10V,$<br>$R_G=6\Omega$ (Note 1,2) | -    | 2.7  | -         | ns       |
| Turn-On Rise Time                                     | $t_r$        |   | -    | 21   | -         |          |
| Turn-Off Delay Time                                   | $t_{d(off)}$ |   | -    | 3.8  | -         |          |
| Turn-Off Fall Time                                    | $t_f$        |   | -    | 18   | -         |          |
| <b>Drain-Source Diode</b>                             |              |   |      |      |           |          |
| Maximum Continuous Drain-Source Diode Forward Current | $I_S$        | ---   | -    | -    | 500       | mA       |
| Diode Forward Voltage                                 | $V_{SD}$     | $I_S=500mA, V_{GS}=0V$  | -    | 0.9  | 1.5       | V        |

**NOTES:**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
4. Guaranteed by design, not subject to production testing



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## TYPICAL CHARACTERISTIC CURVES

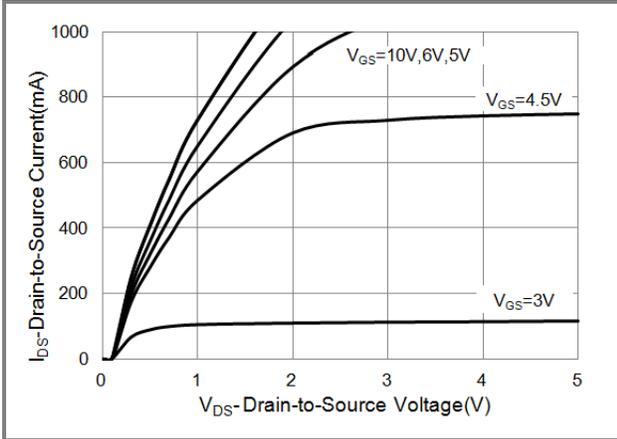


Fig.1 On-Region Characteristics

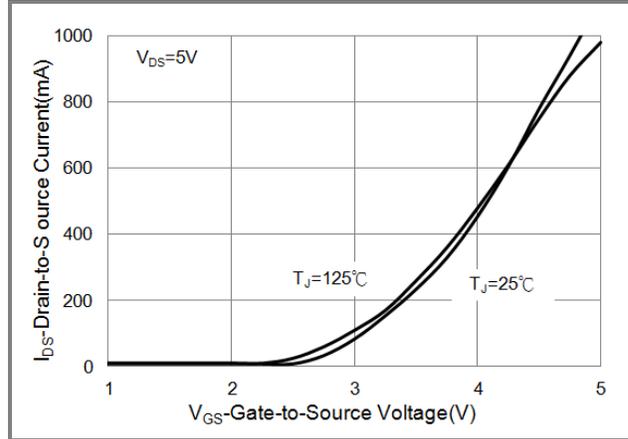


Fig.2 Transfer Characteristics

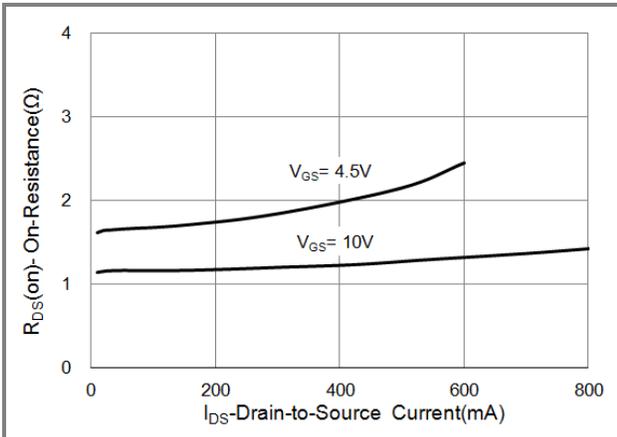


Fig.3 On-Resistance vs. Drain Current

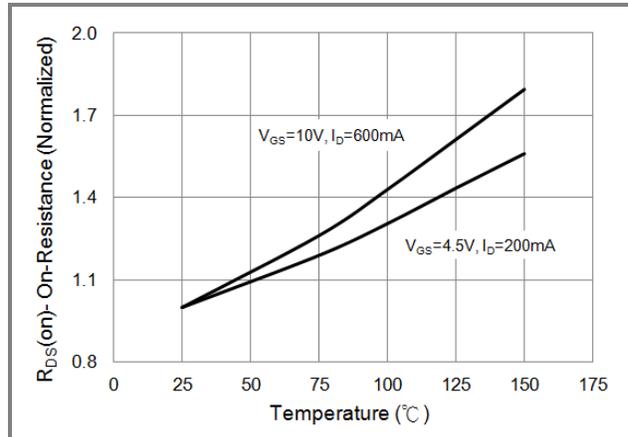


Fig.4 On-Resistance vs. Junction temperature

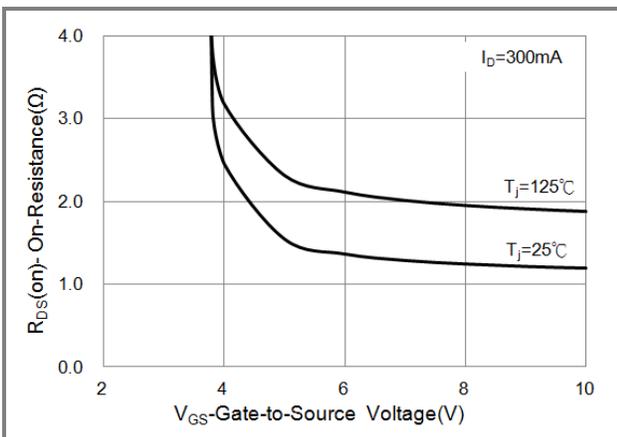


Fig.5 On-Resistance Variation with VGS.

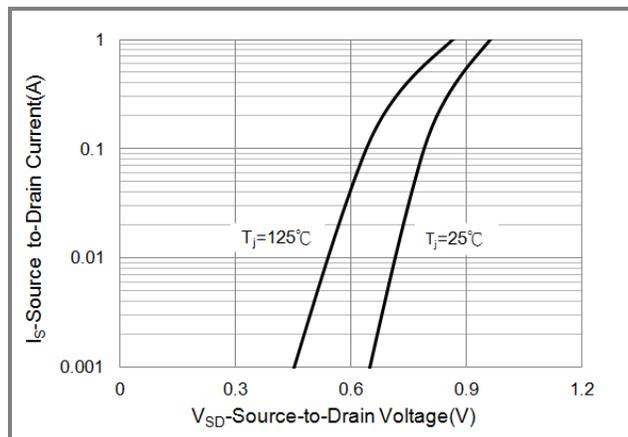


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

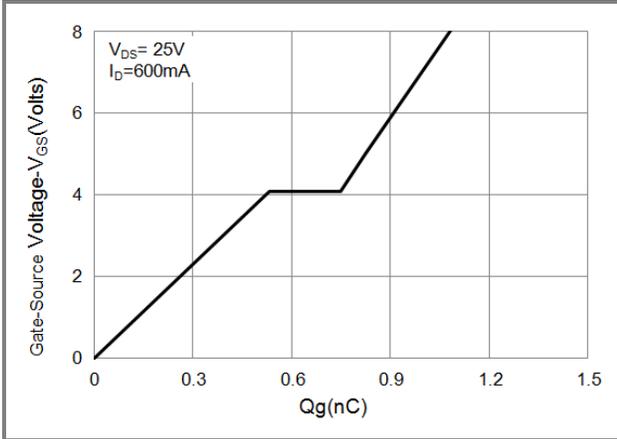


Fig.7 Gate-Charge Characteristics

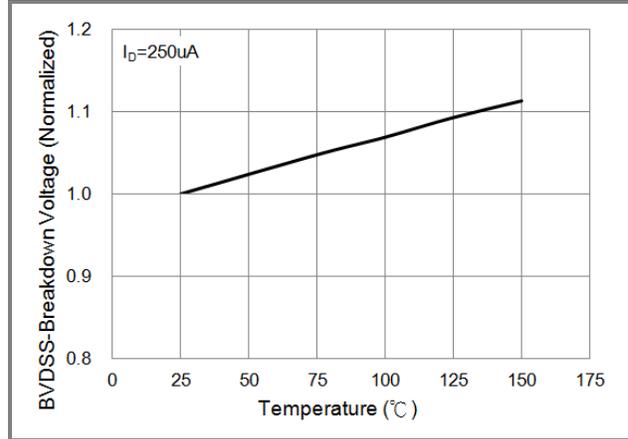


Fig.8 Breakdown Voltage Variation vs. Temperature

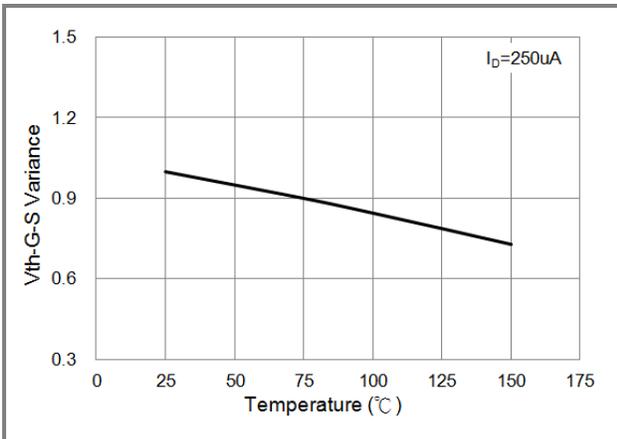


Fig.9 Threshold Voltage Variation with Temperature.

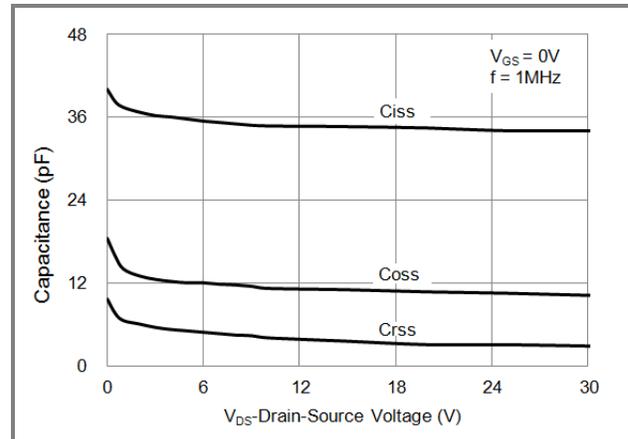


Fig.10 Capacitance vs. Drain-Source Voltage.

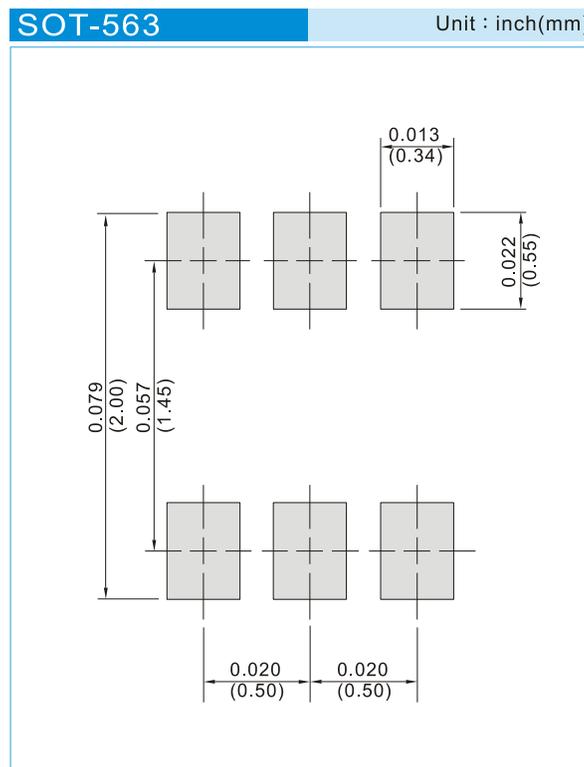


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## Part No Packing Code Version

| Part No Packing Code | Package Type | Packing Type       | Marking | Version      |
|----------------------|--------------|--------------------|---------|--------------|
| PJX8872B_R1_00001    | SOT-563      | 4K pcs / 7" reel   | X2B     | Halogen free |
| PJX8872B_R2_00001    | SOT-563      | 10K pcs / 13" reel | X2B     | Halogen free |

## Mounting Pad Layout





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